EAST - [10665210 non-selective growth for base.wsp:1]

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(1) 09/948877
(1736) "KONINKLIJKE PHILIPS".as.
(1) 10/665210
(61792) (bipolar adj transistor BJT IBJT)
(505929) growth
(90308) epitaxial
(508323) selective
(3751) nonselective
(10682) non adj selective
(13714) nonselective (non adj selective)
(32926) epitaxial adj growth
(47) (nonselective (non adj selective)) adj (epitaxial adj growth)
(29) ((nonselective (non adj selective)) adj (epitaxial adj growth)) and ((bipolar adj tran
(110307) single adj crystal$3 monocrystal$3 mono adj crystal$3
(186733) (polysilicon poly adj silicon polycrystal$4 poly adj crystal$4)
(320407) collector
(17007) (single adj crystal$3 monocrystal$3 mono adj crystal$30
(227) ((single adj crystal$3 monocrystal$3 mono adj crystal$30
(169) (((single adj crystal$3 monocrystal$3 mono adj crystal$30
(17) ((((single adj crystal$3 monocrystal$3 mono adj crystal$30
(2111568) thick$4
(18) ((((single adj crystal$3 monocrystal$3 mono adj crystal$30
(3) "05062981"
(2) 5323032.pn.
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5323032.pn.

Sept - 2004

	U	*	Inventor	Document	Issue	P	Title	Current	CurrentXR	Retrieval	S	C	P					Image Doc.	P
1			Sato, Fumihik	US 5323032	19940	1	Dual layer epitaxtial base heterojunction bipo	257/198	257/588;									US 532303	
2			SATO, F et al	JP 0506299	19930	1	Dual layer epitaxial base HBT has external b											US 532303	

Ready NUM